

Abstract Submitted
for the MAR12 Meeting of
The American Physical Society

First-principles studies of Ce and Eu doped inorganic materials as candidates for scintillator gamma ray detectors¹

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¹The work was supported by the US Department of Homeland Security and was carried out at the Lawrence Berkeley National Laboratory under US Department of Energy Contract No. DE-AC02-05CH11231.

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Date submitted: 11 Nov 2011

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